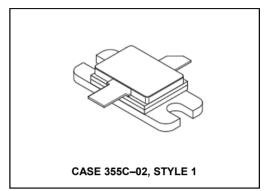


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Designed for 960–1215 MHz long pulse common base amplifier applications such as JTIDS and Mode S transmitters.

- Guaranteed performance @ 1.215 GHz, 36 Vdc Output power = 120 W Peak Gain = 7.6 dB min., 8 .5 dB (typ.)
- 100% tested for load mismatch at all phase angles with 3:1 VSWR
- Hermetically sealed industry standard package
- Silicon nitride passivated
- Gold metalized, emitter ballasted for long life and resistance to metal migration
- Internal input and output matching for broadband operation

#### **Product Image**



#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V <sub>CES</sub>	55	Vdc
Collector–Base Voltage	V <sub>CBO</sub>	55	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	3.5	Vdc
Collector Current — Peak (1)	Ic	15	Adc
Total Device Dissipation @ T <sub>C</sub> = 25°C (1), (2) Derate above 25°C	P <sub>D</sub>	380 2.17	Watts W/°C
Storage Temperature Range	T <sub>stg</sub>	-65 to +200	°C
Junction Temperature	TJ	200	

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case (3)	R <sub>eJC</sub>	0.46	°C/W

#### ELECTRICAL CHARACTERISTICS (T<sub>C</sub> = 25°C unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Breakdown Voltage (I <sub>C</sub> = 60 mAdc, V <sub>BE</sub> = 0)	V <sub>(BR)CES</sub>	55	-	_	Vdc
Collector-Base Breakdown Voltage (I <sub>C</sub> = 60 mAdc, I <sub>E</sub> = 0)	V <sub>(BR)CBO</sub>	55	_	_	Vdc
Emitter–Base Breakdown Voltage (I <sub>E</sub> = 10 mAdc, I <sub>C</sub> = 0)	V <sub>(BR)EBO</sub>	3.5	_	_	Vdc
Collector Cutoff Current (V <sub>CB</sub> = 36 Vdc, I <sub>E</sub> = 0)	Ісво	_	_	25	mAdc

#### NOTES:

(continued)

- 1. Under pulse RF operating conditions.
- 2. These devices are designed for RF operation. The total device dissipation rating applies only when the device is operated as RF amplifiers.
- 3. Thermal Resistance is determined under specified RF operating conditions by infrared measurement techniques.

### MRF10120



# Microwave Long Pulse Power Silicon NPN Transistor 120W (peak), 960–1215MHz

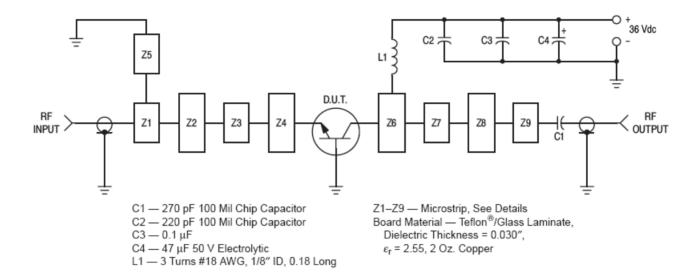
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#### ELECTRICAL CHARACTERISTICS — continued (T<sub>C</sub> = 25°C unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
ON CHARACTERISTICS	•	•		•	
DC Current Gain (I <sub>C</sub> = 5.0 Adc, V <sub>CE</sub> = 5.0 Vdc)	h <sub>FE</sub>	20	_	_	_
FUNCTIONAL TESTS (7.0 μs Pulses @ 54% duty cycle for 3.4 ms	then off for 4.5	ms; overall d	uty cycle = 23°	%)	
Common–Base Amplifier Power Gain (V <sub>CC</sub> = 36 Vdc, P <sub>out</sub> = 120 W Peak, f = 1215 MHz)	G <sub>PB</sub>	7.6	8.5	_	dB
Collector Efficiency (V <sub>CC</sub> = 36 Vdc, P <sub>out</sub> = 120 W Peak, f = 1215 MHz)	η	50	55	_	%
Load Mismatch (V <sub>CC</sub> = 36 Vdc, P <sub>out</sub> = 120 W Peak, f = 1215 MHz, VSWR = 3:1 All Phase Angles)	Ψ	No Degradation in Output Power			



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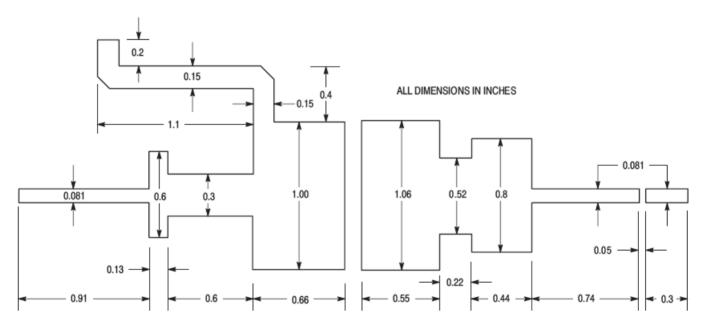
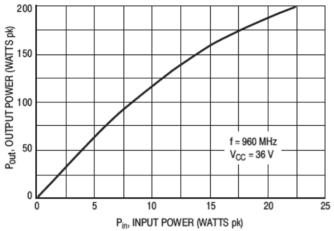


Figure 1. Test Circuit



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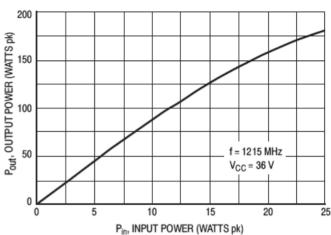


Figure 2. Output Power versus Input Power

Figure 3. Output Power versus Input Power

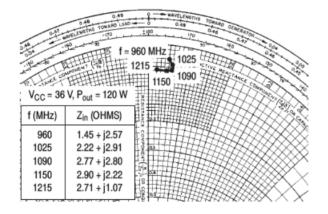
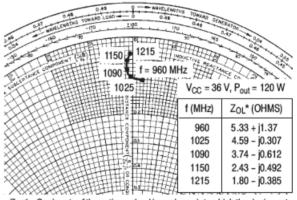


Figure 4. Series Equivalent Input Impedances



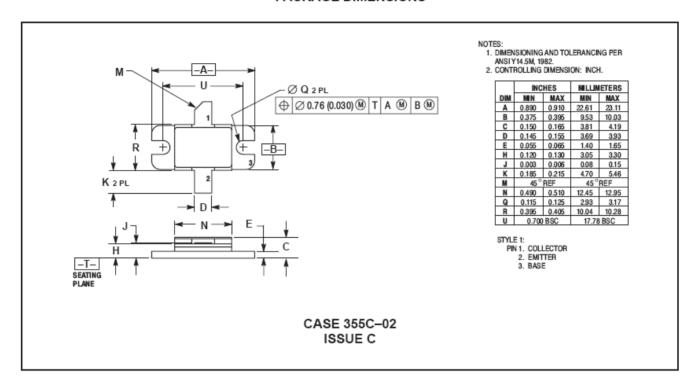
 $Z_{OL}^{\star}$  = Conjugate of the optimum load impedance into which the device output operates at a given output power, voltage and frequency.

Figure 5. Series Equivalent Output Impedance



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#### PACKAGE DIMENSIONS



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Microwave Long Pulse Power Silicon NPN Transistor 120W (peak), 960–1215MHz

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